

FEATURES

- Low Offset Voltage 0.3mV Typ, 0.8mV Max
- Low Offset Current 0.3nA Typ, 3nA Max
- Low Bias Current 28nA Typ, 50nA Max
- Low Offset Drift $1\mu\text{V}/^\circ\text{C}$, $4\text{pA}/^\circ\text{C}$
- High Gain 200,000 Min
- High CMRR 110dB Typ, 94dB Min
- High Input Impedance $16\text{M}\Omega$
- Fast Response Time 190ns Typ, 270ns Max
- Standard Power Supplies $+5\text{V}$ or $\pm 5\text{V}$ to $\pm 18\text{V}$
- Guaranteed Operation from Single $+5\text{V}$
- No Pull-Up Resistor Required for TTL Drive
- Wired OR Capability
- Fits 111, 106, 710 Sockets
- Easy Offset Nulling Single $2\text{k}\Omega$ Potentiometer
- Easy to Use Free from Oscillations
- Available in Die Form

ORDERING INFORMATION [†]

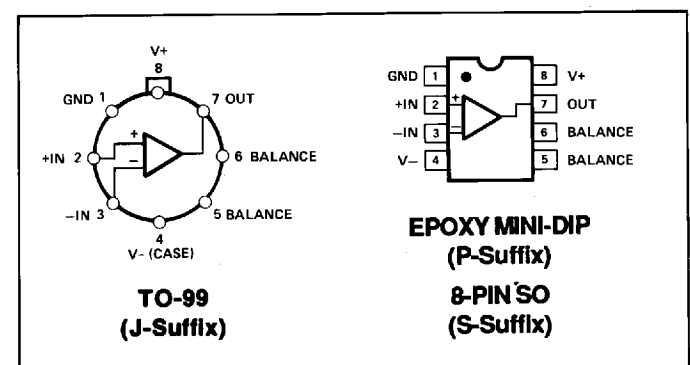
$T_A = +25^\circ\text{C}$ V_{OS} MAX (mV)	PACKAGE			OPERATING TEMPERATURE RANGE
	TO-99	PLASTIC 8-PIN	SO 8-PIN	
0.8	—	CMP02EP	—	COM
2.8	CMP02CJ	CMP02CP	CMP02CS	XIND

[†] Burn-in is available on commercial and industrial temperature range parts in CerDIP, plastic DIP, and TO-can packages.

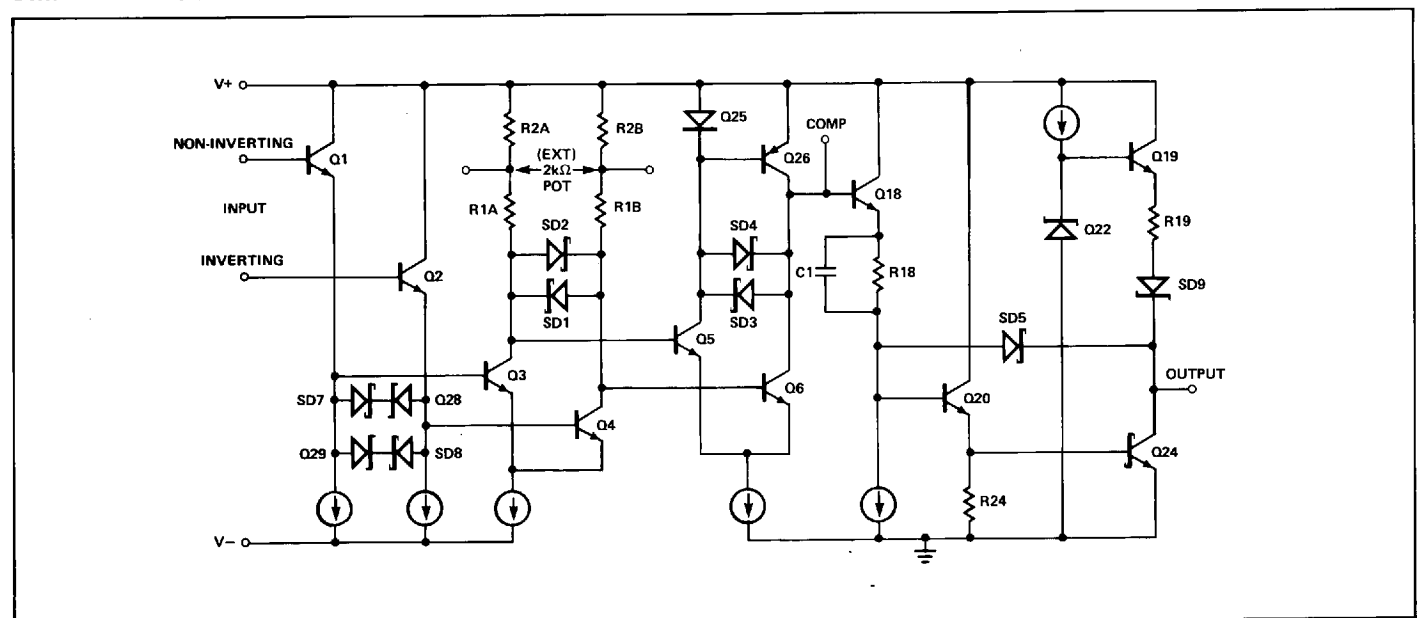
GENERAL DESCRIPTION

The CMP-02 is a monolithic low input current comparator using an advanced NPN-Schottky Barrier Diode process. It features superior input characteristics with extremely low offset voltage, offset current, bias current and temperature drift. High common-mode and power supply rejection plus good response time contribute to excellent performance in the most demanding applications. The balanced offset nulling, large output drive, and wired-OR capability combined with internal pull-up maximize application convenience. The CMP-02 is capable of operating over a wide range of supply voltages, including single plus 5 volt supply operation, and is pin-compatible to earlier 111, 106, and 710 types. For applications requiring faster response time, please refer to the CMP-01 fast precision comparator data sheet.

PIN CONNECTIONS



SIMPLIFIED SCHEMATIC



CMP-02

ABSOLUTE MAXIMUM RATINGS (Note 1)

Total Supply Voltage, V_+ to V_-	36V
Output to Ground	-5V to +32V
Output to Negative Supply Voltage	50V
Ground to Negative Supply Voltage	30V
Positive Supply Voltage to Ground	30V
Positive Supply Voltage to Offset Null	0 to 2V
Differential Input Voltage	$\pm 11V$
Input Voltage ($V_S = \pm 15V$)	$\pm 15V$
Output Sink Current (Continuous Operation)	75mA
Operating Temperature Range	
CMP-02E	0°C to +70°C
CMP-02C	-40°C to +85°C
Junction Temperature (T_J)	-65°C to +150°C
Storage Temperature Range	-65°C to +150°C
P-Suffix	-65°C to +125°C

Lead Temperature (Soldering, 60 sec)	300°C
Output Short-Circuit Duration	
To Ground	Indefinite
To V_+	1 Minute

PACKAGE TYPE	θ_{JA} (Note 2)	θ_{JC}	UNITS
TO-99 (J)	150	18	°C/W
8-Pin Plastic DIP (P)	103	43	°C/W
8-Pin SO (S)	158	43	°C/W

NOTES:

1. Absolute ratings apply to both DICE and packaged parts, unless otherwise noted.
2. θ_{JA} is specified for worst case mounting conditions, i.e., θ_{JA} is specified for device in socket for TO and P-DIP packages; θ_{JA} is specified for device soldered to printed circuit board for SO package.

ELECTRICAL CHARACTERISTICS at $V_S = \pm 15V$, $T_A = 25^\circ C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	CMP-02E			CMP-02C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{OS}	$R_S \leq 5k\Omega$, (Note 1)	—	0.3	0.8	—	0.4	2.8	mV
Input Offset Voltage	V_{OS}	$R_S \leq 50k\Omega$, (Note 1)	—	0.3	0.9	—	0.4	3	mV
Input Offset Current	I_{OS}	(Note 1)	—	0.3	3.0	—	0.4	15	nA
Input Bias Current	I_B		—	28	50	—	35	100	nA
Differential Input Resistance	R_{IN}	(Note 2)	1.7	3	—	0.9	2	—	M Ω
Voltage Gain	A_V	$V_O = 1$ to 3V, (Note 2)	200	500	—	100	500	—	V/mV
Response Time (Note 3)	t_r	100mV step, 5mV Overdrive	—	190	270	—	190	270	ns
		No Load (No Pull-Up)	—	190	—	—	190	—	
		5k Ω to 5V (Pull-Up)	—	190	—	—	190	—	
		TTL Fan-Out = 4, No Pull-Up	—	190	—	—	190	—	
Input Slew Rate			—	15	—	—	15	—	V/ μs
Input Voltage Range	CMVR		± 12.5	± 13.0	—	± 12.5	± 13.0	—	V
Common-Mode Rejection Ratio	CMRR		94	110	—	90	110	—	dB
Power Supply Rejection Ratio	PSRR	$5V \leq V_{S+} \leq 18V$, $-18V \leq V_{S-} \leq 0V$	80	100	—	74	98	—	dB
Positive Output Voltage	V_{OH}	$V_{IN} \geq 3mV$, $I_O = 320\mu A$	2.4	3.2	—	—	—	—	V
		$V_{IN} \geq 3mV$, $I_O = 240\mu A$	—	—	—	2.4	3.4	—	
		$V_{IN} \geq 3mV$, $I_O = 0mA$	2.4	4.8	—	2.4	4.8	—	
Saturation Voltage	V_{OL}	$V_{IN} \leq -10mV$, $I_{sink} = 0mA$	—	0.16	0.40	—	0.16	0.40	V
		$V_{IN} \leq -10mV$, $I_{sink} \leq 6.4mA$	—	0.3	0.45	—	0.31	0.45	
		$V_{IN} \leq -10mV$, $I_{sink} \leq 12mA$ (CMP-02 only)	—	0.36	0.5	—	—	—	
Output Leakage Current	I_{LEAK}	$V_{IN} \geq 10mV$, $V_O = +30V$	—	0.03	2.0	—	0.05	8.0	μA
Positive Supply Current	I_+	$V_{IN} \leq -10mV$	—	5.5	8.0	—	5.6	8.5	mA
Negative Supply Current	I_-	$V_{IN} \leq -10mV$	—	1.1	2.2	—	1.2	2.2	mA
Power Dissipation	P_d	$V_{IN} \leq -10mV$	—	99	153	—	102	161	mW
Offset Voltage Adjustment Range		Nulling Pot $\geq 2k\Omega$	—	± 5	—	—	± 5	—	mV

NOTES:

1. These Parameters are specified as the maximum values required to drive the output between the logic levels of 0.4V and 2.4V with a 1k Ω load tied to +5V; thus, these parameters define an error band which takes into

account the worst case effects of voltage gain and input impedance.

2. Guaranteed by design.
3. Sample tested.

ELECTRICAL CHARACTERISTICS at $V_S = 5V$, $V_{S-} = 0V$, $T_A = 25^\circ C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	CMP-02E			CMP-02C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{OS}	$R_S \leq 5k\Omega$, (Note 1)	—	0.4	1.5	—	0.5	3.5	mV
Input Offset Current	I_{OS}	(Note 1)	—	0.25	3	—	0.35	14	nA
Input Bias Current	I_B		—	24	45	—	30	90	nA
Voltage Gain	A_V	$V_O = 1$ to 3V	—	50	—	—	50	—	V/mV
Response Time	t_r	100mV Step, 5mV Overdrive	—	250	—	—	250	—	ns
		5k Ω to 5V (Pull-Up) TTL Fan-Out = 4, 5k Ω to 5V	—	250	—	—	250	—	
Input Voltage Range	CMVR		1.8-3.5	1.7-3.8	—	1.8-3.5	1.7-3.8	—	V
Saturation Voltage	V_{OL}	$V_{IN} \leq -3.5mV$, $I_{sink} \leq 6.4mA$	—	0.3	0.45	—	0.3	0.45	V
Positive Supply Current	I_+	$V_{IN} \leq -10mV$	—	2.2	3	—	2.3	3.6	mA
Power Dissipation	P_d	$V_{IN} \leq -10mV$	—	11	15	—	11.5	18	mW

NOTE:

1. These Parameters are specified as the maximum values required to drive the output between the logic levels of 0.4V and 2.4V with a 1k Ω load tied to +5V; thus, these parameters define an error band which takes into account the worst case effects of voltage gain and input impedance.

ELECTRICAL CHARACTERISTICS $V_S = \pm 15V$, $0^\circ C \leq T_A \leq +70^\circ C$ for E Grade, $-40^\circ C \leq T_A \leq +85^\circ C$ for C Grade, unless otherwise noted.

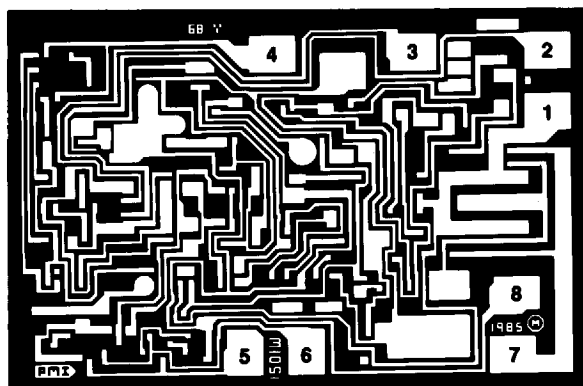
PARAMETER	SYMBOL	CONDITIONS	CMP-02E			CMP-02C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{OS}	$R_S \leq 5k\Omega$, (Note 1)	—	0.4	1.4	—	0.5	3.5	mV
		$V_{S+} = 5V$, $V_{S-} = 0V$, (Note 1)	—	0.5	2.4	—	0.6	4.3	
Average Input Offset Voltage Drift									
Without External Trim	TCV_{OS}	$R_S = 50\Omega$	—	1.5	—	—	1.8	—	$\mu V/^\circ C$
With External Trim	TCV_{OSn}	$R_S = 50\Omega$	—	1	—	—	1.2	—	
Input Offset Current	I_{OS}	$T_A = +70^\circ C$, (Note 1)	—	0.3	3	—	0.4	15	nA
		$T_A = 0^\circ C$, (Note 1)	—	0.4	6	—	0.5	25	
Average Input Offset Current Drift	TCI_{OS}	$+25^\circ C \leq T_A \leq +70^\circ C$	—	2	—	—	3	—	$pA/^\circ C$
		$0^\circ C \leq T_A \leq +25^\circ C$	—	4	—	—	5	—	
Input Bias Current	I_B	$T_A = +70^\circ C$	—	26	50	—	33	100	nA
		$T_A = 0^\circ C$	—	34	80	—	42	160	
Voltage Gain	A_V	$V_O = 1$ to 3V, (Note 2)	100	500	—	70	500	—	V/mV
Response Time	t_r	100mV Step, 5mV Overdrive	—	225	—	—	225	—	ns
		$T_A = +70^\circ C$, No Load $T_A = 0^\circ C$, No Load	—	180	—	—	180	—	
Input Voltage Range	CMVR		± 12.0	± 13	—	± 12	± 13	—	V
Common-Mode Rejection Ratio	CMRR		90	108	—	86	108	—	dB
Power Supply Rejection Ratio	PSRR	$5V \leq V_{S+} \leq 15V$, $-15V \leq V_{S-} \leq 0V$	77	98	—	70	88	—	dB
Positive Output Voltage	V_{OH}	$V_{IN} \geq 4mV$, $I_O = 200\mu A$	2.4	3.2	—	2.4	3.2	—	V
Saturation Voltage	V_{OL}	$V_{IN} \leq -10mV$, $I_{sink} = 0$	—	0.17	0.4	—	0.17	0.4	V
		$V_{IN} \leq -10mV$, $I_{sink} = 6.4mA$	—	0.30	0.5	—	0.31	0.5	

NOTES:

1. These Parameters are specified as the maximum values required to drive the output between the logic levels of 0.4V and 2.4V with a 1k Ω load tied to +5V; thus, these parameters define an error band which takes into account the worst case effects of voltage gain and input impedance.
2. Guaranteed by design.

CMP-02

DICE CHARACTERISTICS



DIE SIZE 0.065 x 0.043 inch, 2730 sq. mils
(1.651 x 1.094 mm, 1.806 sq. mm)

1. GROUND
2. NONINVERTING INPUT
3. INVERTING INPUT
4. NEGATIVE SUPPLY (SUBSTRATE)
5. BALANCE
6. BALANCE
7. OUTPUT
8. POSITIVE SUPPLY

WAFER TEST LIMITS at $V_S = \pm 15V$, $T_A = 25^\circ C$.

PARAMETER	SYMBOL	CONDITIONS	CMP-02N LIMIT	CMP-02GR LIMIT	UNITS
Input Offset Voltage	V_{OS}	$R_S \leq 5k\Omega$ $R_S \leq 50k\Omega$	0.8 0.9	2.8 3	mV MAX
Input Offset Current	I_{OS}		3	15	nA MAX
Input Bias Current	I_B		50	100	nA MAX
Differential Input Resistance	R_{IN}		1.7	0.9	M Ω MIN
Input Voltage Range	CMVR		± 12.5	± 12.5	V MIN
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm CMVR$	94	90	dB MIN
Power Supply Rejection Ratio	PSRR	$5V \leq V_S \leq 18V$ $-18V \leq V_S \leq 0V$	80	74	dB MIN
Positive Output Voltage	V_{OH}	$V_{IN} \geq 3mV$, $I_O = 320\mu A$ $V_{IN} \geq 3mV$, $I_O = 240\mu A$	2.4 —	— 2.4	V MIN
Saturation Voltage	V_{OL}	$I_{sink} = 6.4mA$	0.45	0.45	V MAX
Output Leakage Current	I_{LEAK}	$V_{IN} \geq 10mV$, $V_O = 30V$	2	8	μA MAX
Positive Supply Current	I_+	$V_{IN} \leq -10mV$	8	8.5	mA MAX
Negative Supply Current	I_-	$V_{IN} \leq -10mV$	2.2	2.2	mA MAX
Power Consumption	P_d	$V_{IN} \leq -10mV$	153	161	mW MAX

WAFER TEST LIMITS at $V_{S+} = 5V$ and $V_{S-} = 0V$, $T_A = 25^\circ C$.

PARAMETER	SYMBOL	CONDITIONS	CMP-02N LIMIT	CMP-02GR LIMIT	UNITS
Input Offset Voltage	V_{OS}	$R_S \leq 5k\Omega$	1.5	3.5	mV MAX
Input Offset Current	I_{OS}		3	14	nA MAX

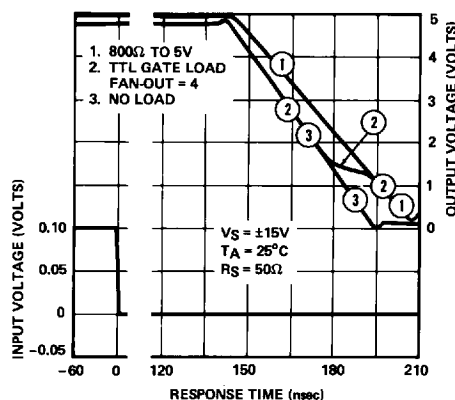
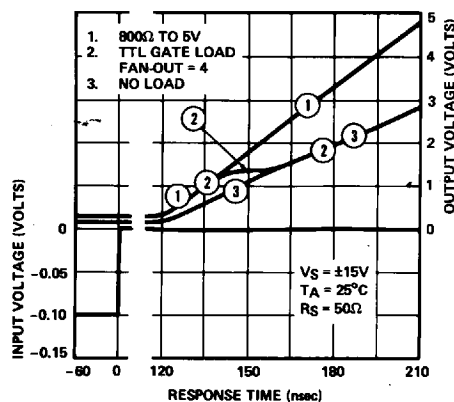
NOTE:

Electrical tests are performed at wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard product dice. Consult factory to negotiate specifications based on dice lot qualification through sample lot assembly and testing.

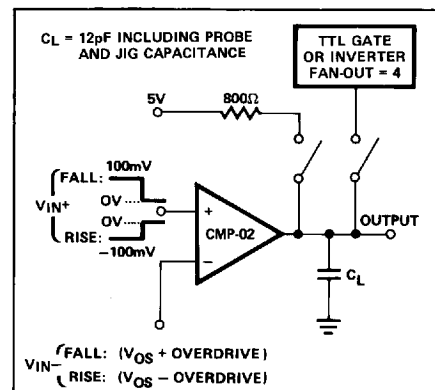
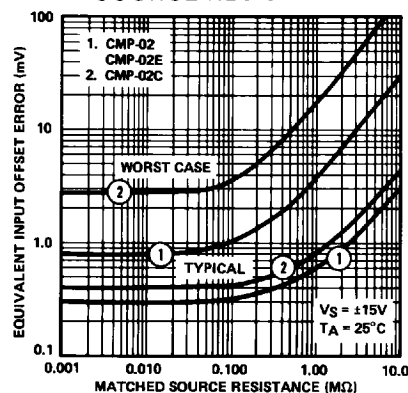
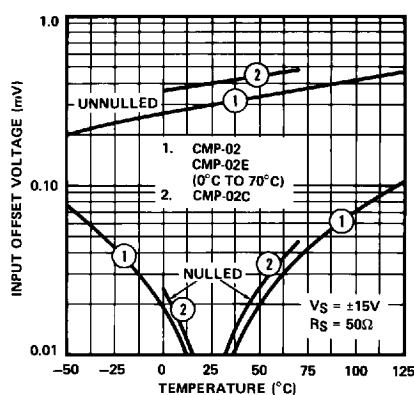
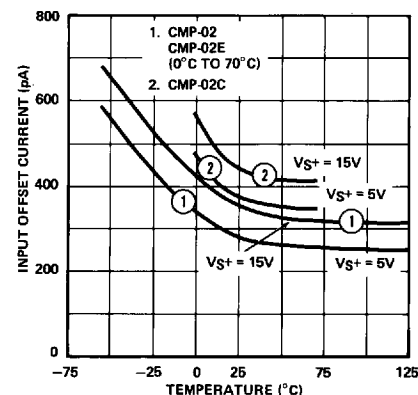
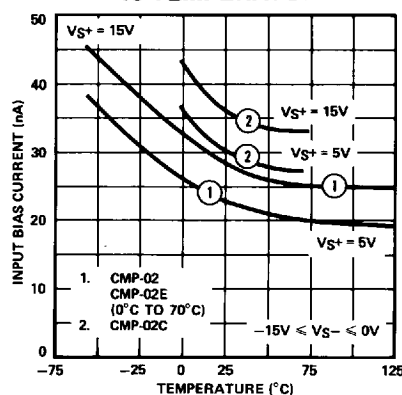
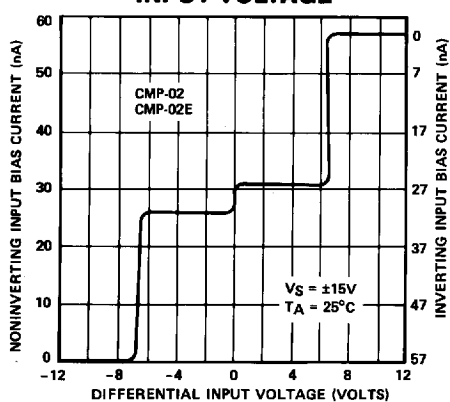
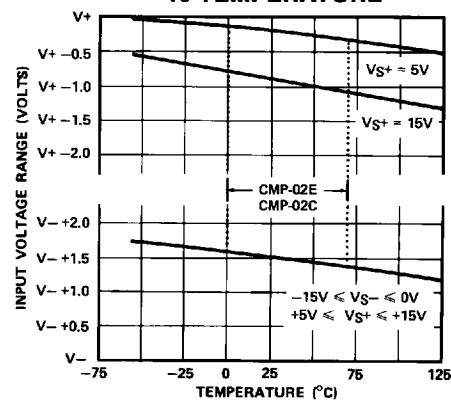
TYPICAL ELECTRICAL CHARACTERISTICS at $V_S = \pm 15V$.

PARAMETER	SYMBOL	CONDITIONS	CMP-02N TYPICAL	CMP-02GR TYPICAL	UNITS
Average Input Offset Voltage Drift	TCV_{OS}	$R_S = 50\Omega$	1.5	1.8	$\mu V/^\circ C$
Average Input Offset Current Drift	TCI_{OS}		4	5	pA/ $^\circ C$
Response Time	t_r	100mV Step, 5mV Overdrive No Load (No Pull-Up), $T_A = 25^\circ C$	190	190	ns

TYPICAL PERFORMANCE CHARACTERISTICS

**RESPONSE TIME,
100mV STEP, 5mV OVERDRIVE, VARIOUS LOADS**


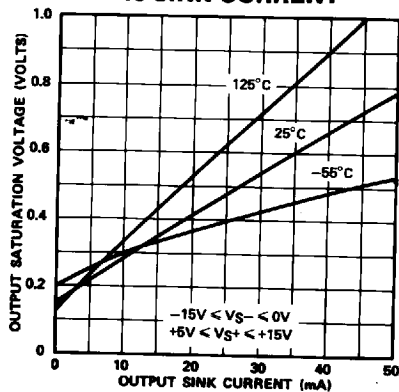
RESPONSE TIME TEST CIRCUIT


**INPUT OFFSET ERROR vs
SOURCE RESISTANCE**

**OFFSET VOLTAGE vs
TEMPERATURE**

**INPUT OFFSET CURRENT
vs TEMPERATURE**

**INPUT BIAS CURRENT
vs TEMPERATURE**

**INPUT BIAS CURRENT
vs DIFFERENTIAL
INPUT VOLTAGE**

**INPUT VOLTAGE RANGE
vs TEMPERATURE**


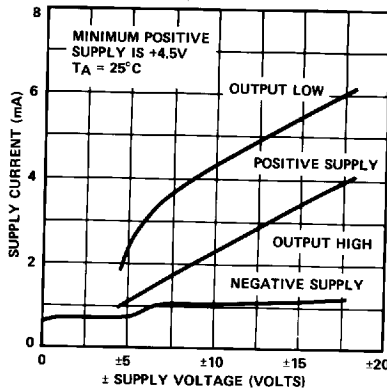
CMP-02

TYPICAL PERFORMANCE CHARACTERISTICS

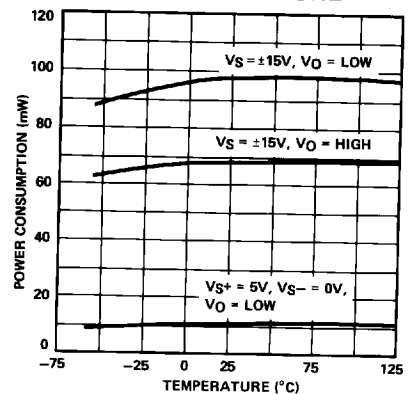
SATURATION VOLTAGE vs SINK CURRENT



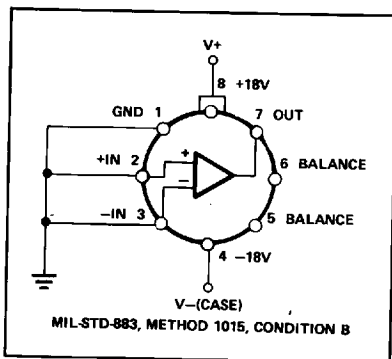
SUPPLY CURRENT vs SUPPLY VOLTAGE



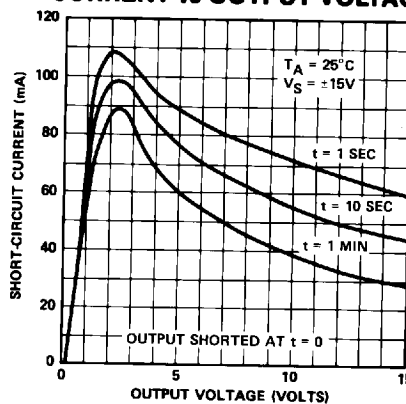
POWER CONSUMPTION vs TEMPERATURE



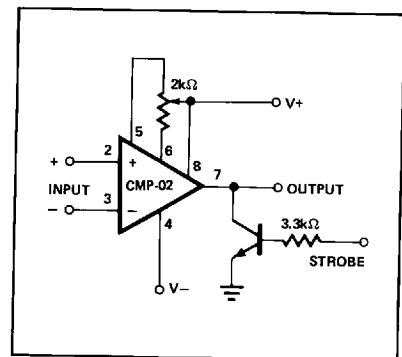
STANDARD BURN-IN CIRCUIT



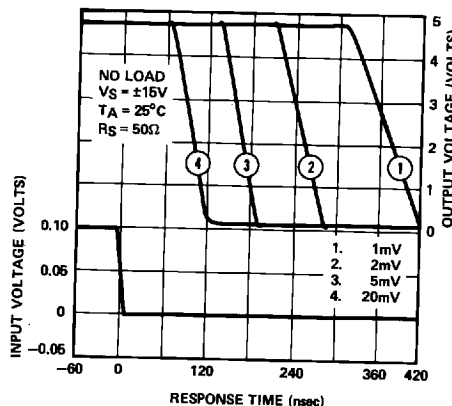
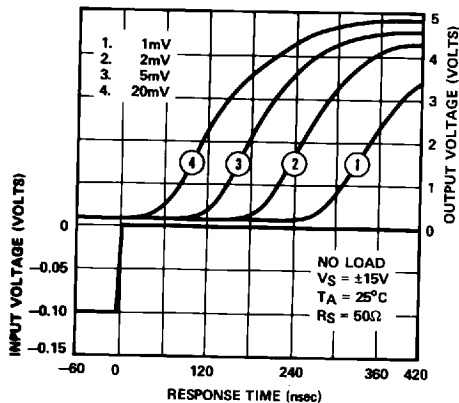
OUTPUT SHORT-CIRCUIT CURRENT vs OUTPUT VOLTAGE



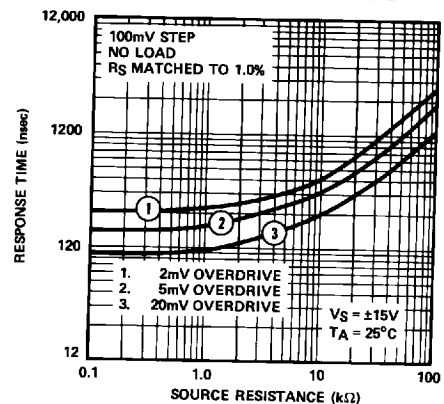
OFFSET TRIMMING AND STROBE CIRCUITS



RESPONSE TIME, 100mV STEP AND VARIOUS INPUT OVERDRIVES



RESPONSE TIME vs SOURCE RESISTANCE



APPLICATIONS INFORMATION

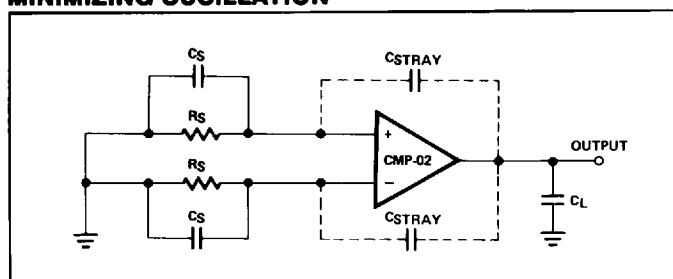
The CMP-02 provides fast response times even with small overdrives; to achieve this performance requires very high gain at high frequencies. The CMP-02 is completely free of oscillations; however, small values of stray capacitance from output to input when combined with high-source resistances can cause an unstable condition. DC characteristics are not affected, but when the input is within a few microvolts of the transition level, certain conditions can create an oscillation region. The width of this oscillatory region and the size of source resistance where oscillations begin is a strong function of the stray coupling present. The following suggestions are offered as a guide towards minimizing the conditions for oscillation: matched source resistors, minimized stray capacitances (e.g., a ground plane between output and input), or capacitive output loading (C_L). The capacitive loading techniques will eliminate the oscillations, but result in slower

response time. Matched bypass capacitors across the input resistors also can eliminate the instability,

$$\text{and if } C_S \geq 20\text{pF} \left(\frac{\text{maximum step size}}{\text{minimum overdrive}} \right)$$

the response time will approximate the response time for low values of R_S . It should be noted that the offset nulling terminals do not require bypassing for stability. As with all wideband circuits, it is recommended that the supplies be bypassed near the socket of the device.

MINIMIZING OSCILLATION



PRECISION, DUAL LIMIT, GO/NO GO TESTER

